NSN 5961-00-484-8742

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View Online at https://aerobasegroup.com/nsn/5961-00-484-8742 **Inclosure Material:** Metal **Overall Length:** 1.803 inches **Overall Diameter:** 0.844 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.844 inches and 0.875 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 250.0 collector to base voltage/static/emitter open and 250.0 collector to emitter voltage, dc with specified circuit between base and emitter and 250.0 collector-to-emitter, substaining voltage, base open-circuited **Current Rating Per Characteristic:** Between 7.50 amperes source cutoff current and 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 200.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius case **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:** 80131-release4201 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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